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# RJP4301APP

## Nch IGBT for Strobe Flash

REJ03G1709-0300 Rev.3.00 Oct 14, 2009

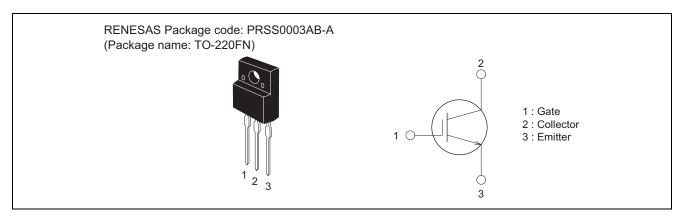
### **Features**

• V<sub>CES</sub>: 430 V

• TO-220FN package

• High Speed Switching

### **Outline**



## **Applications**

Strobe flash

## **Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

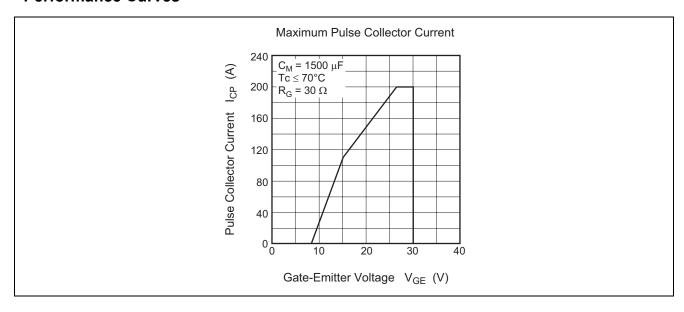
Parameter	Symbol	Ratings	Unit	Conditions
Collector-emitter voltage	$V_{CES}$	430	V	V <sub>GE</sub> = 0 V
Gate-emitter voltage	V <sub>GES</sub>	±33	V	V <sub>CE</sub> = 0 V, Refer to item 4 under Notes on the Actual Specifications
Collector current (Pulse)	I <sub>CM</sub>	200	А	$C_M$ = 1500 $\mu$ F (see performance curve)
Maximum power dissipation	Pc	30	W	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	– 40 to +150	°C	
Mass	_	2.0	g	Typical value

## **Electrical Characteristics**

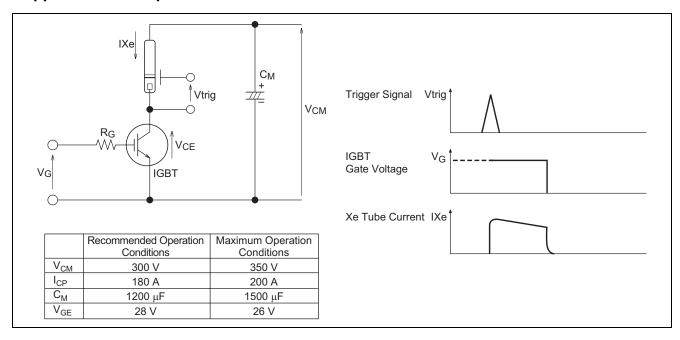
 $(Tj = 25^{\circ}C)$ 

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Collector-emitter breakdown voltage	V <sub>(BR)CES</sub>	430	_	_	V	$I_C = 100 \mu A, V_{GE} = 0 V$
Collector-emitter leakage current	I <sub>CES</sub>	_	_	1	μΑ	V <sub>CE</sub> = 430 V, V <sub>GE</sub> = 0 V
Gate-emitter leakage current	I <sub>GES</sub>	_	_	±0.1	μΑ	$V_{GE} = \pm 33 \text{ V}, V_{CE} = 0 \text{ V}$
Gate-emitter threshold voltage	$V_{\text{GE(th)}}$	3.0	_	5.5	V	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	_	4.0	10	V	I <sub>C</sub> = 200 A, V <sub>GE</sub> = 26 V
Input capacitance	Cies	_	1150	_	pF	V <sub>CE</sub> = 25 V
Output capacitance	Coes	_	125	_	pF	V <sub>GS</sub> = 0
Reverse transfer capacitance	Cres	_	14	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d(on)</sub>	_	0.01	_	μS	I <sub>D</sub> = 200 A
Rise time	tr	_	0.06	_	μS	V <sub>GS</sub> = 26 V
Turn-off delay time	t <sub>d(off)</sub>	_	0.15	_	μS	V <sub>CC</sub> = 300 V
Fall time	t <sub>f</sub>	_	0.2	_	μS	$R_G = 25 \Omega$

### **Performance Curves**



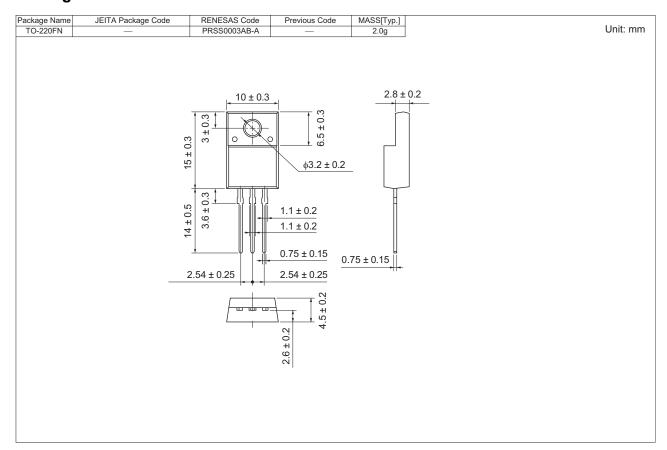
## **Application Example**



### **Precautions on Usage**

- 1. Gate drive voltage during on-period must be applied to satisfy the rating of maximum pulse collector current. And peak reverse gate current during turn-off must become less than 1 A. (In general, when  $R_{G(off)} = 30 \Omega$ , it is satisfied.)
- 2. IGBT has MOS structure and its gate is insulated by thin silicon oxide. So please handle carefully to protect the device from electrostatic charge.
- 3. The operation life should be endured until repeated discharge of 5,000 times under the charge current ( $I_{Xe} \le 200 \text{ A}$ : full luminescence condition) of main capacitor. Repetition period under full luminescence condition is over 3 seconds
- 4. Total operation hours applied to the gate-emitter voltage must be within 5,000 hours.

## **Package Dimensions**



## **Ordering Information**

Part No.	Quantity	Shipping Container
RJP4301APP-00-T2	50 pcs	Magazine (Tube)

Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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### Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

**Renesas Technology Taiwan Co., Ltd.** 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510